



Product data sheet

1. General description

WMS30N250K is a high performance logic level N-channel MOSFET in SOT23 package, which utilizes advanced Trench MOSFET technology to provide low $R_{DS(on)}$ and gate charge. It is designed and qualified in a wide range of industrial and consumer applications.



2. Features and benefits

- Advance High Cell Density Trench Technology
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Switching Losses
- Optimized Gate Charge to Minimize Driver Losses
- RoHS Compliant and Halogen Free and Lead Free

3. Applications

- Load Switch
- General PWM Applications

4. Quick reference data

Table 1. Qu	uick reference data							
Symbol	Parameter	Conditions	Notes	Values			Unit	
Absolute	maximum rating							
V _{DS}	drain-source voltage				30	·	V	
V _{GS}	gate-source voltage				±20		V	
I _D	continuous drain current	V _{GS} = 10 V; T _a = 25 °C			5.9		А	
P _{tot}	power dissipation	T _a = 25 °C		1.4		W		
T _j	junction temperature			-55 to 150		°C		
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static cha	aracteristics							
$R_{\text{DS(on)}}$	drain-source on-state	V _{GS} = 10 V, I _D = 5.9 A		-	18	25	mΩ	
	resistance	V _{GS} = 4.5 V, I _D = 3 A		-	26	35	mΩ	
Dynamic o	Dynamic characteristics							
Q _{G(tot)}	total gate charge	I_{D} = 5.9 A; V_{DS} = 15 V; V_{GS} = 10 V		-	11	-	nC	

5. Pinning information

Fable 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	2	D			
2	S	source					
3	D	drain		G sym300 S			

6. Ordering information

Table 3. Ordering information							
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
WMS30N250K	SOT23	WMS30N250KX	Reel	3000	SOT23L	22-Aug-2022	

7. Marking

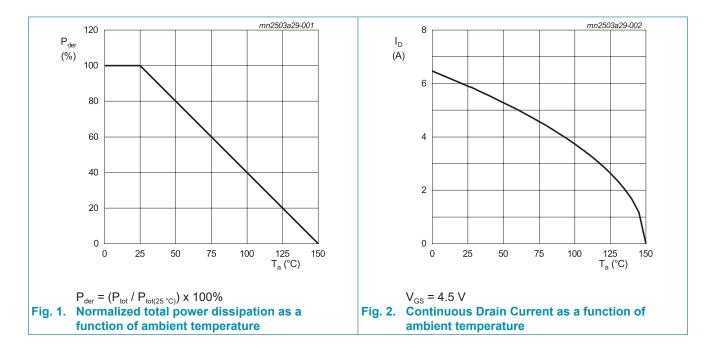
Table 4. Marking codes							
Type number	Marking codes						
WMS30N250K	AE						

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DS}	drain-source voltage			30	V
V _{GS}	gate-source voltage			±20	V
I _D	continuous drain current	V _{GS} = 10 V; T _a = 25 °C		5.9	А
		V _{GS} = 10 V; T _a = 70 °C		4.7	А
I _{DM}	pulsed drain current	t _p = 10 μs; T _a = 25 °C		23.6	А
P _{tot}	power dissipation	T _a = 25 °C		1.4	W
T _{stg}	storage temperature			-55 to 150	°C
T _j	junction temperature			-55 to 150	°C

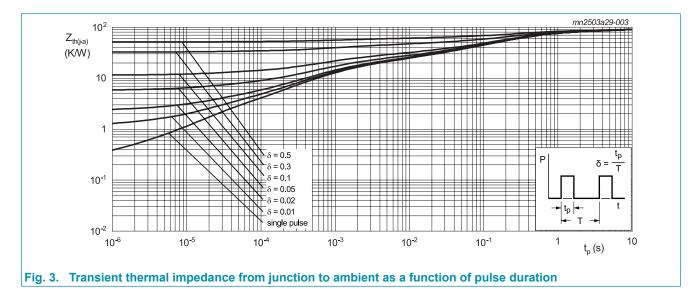


9. Thermal & Mechanical characteristics

	able 6. Thermal & Mechanical Characteristics							
Symbol	Parameter	Conditions	Notes	Min	Тур	Мах	Unit	
R _{th(j-a)}	thermal resistance from junction to ambient	t ≤ 10s	[1]	-	72	90	K/W	
		in free air	[1]	-	95	120	K/W	

Table 6. Thermal & Mechanical characteristics

[1] Surface mount on FR4 board of 1 inch², 1 oz copper.

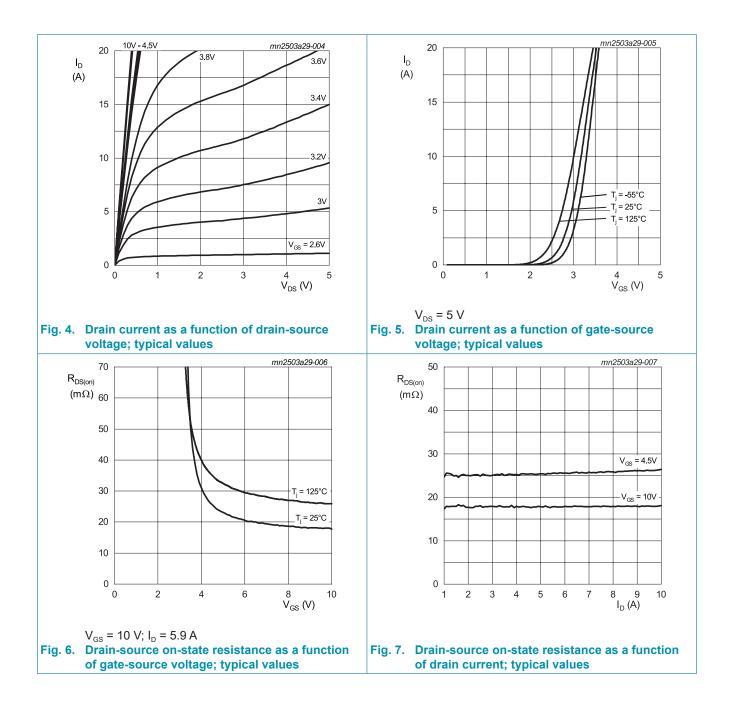


10. Characteristics

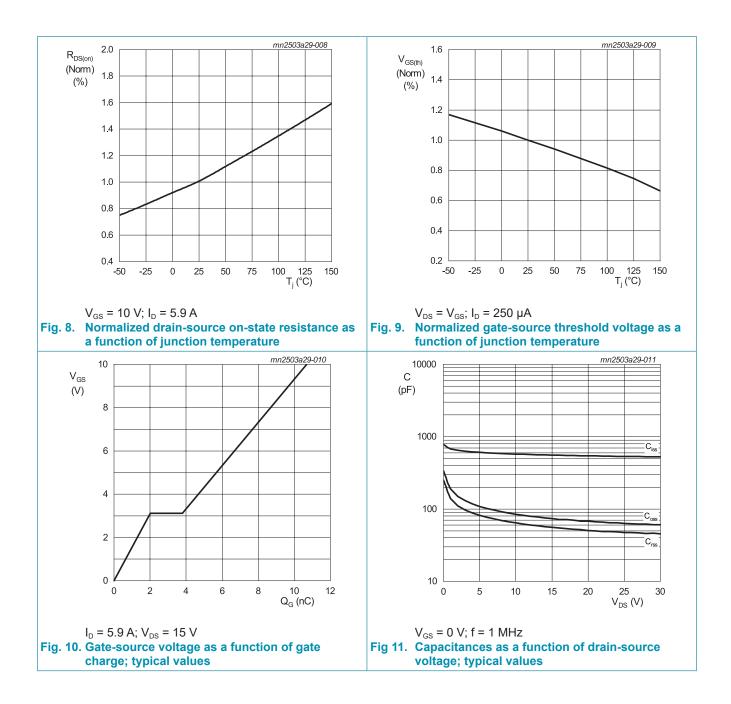
Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{(\text{BR})\text{DSS}}$	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V		30	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS}		1	1.5	2.4	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V		-	-	1	μA
		V _{DS} = 30 V; V _{GS} = 0 V; T _j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state	V _{GS} = 10 V; I _D = 5.9 A		-	18	25	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 3 A		-	26	35	mΩ
R _G	gate resistance	f = 1 MHz		-	2.4	-	Ω
Dynamic	characteristics	·					
Q _{G(tot)}	total gate charge	I_{D} = 5.9 A; V_{DS} = 15 V; V_{GS} = 10 V		-	11	-	nC
Q _{GS}	gate-source charge			-	2.0	-	nC
Q_{GD}	gate-drain charge			-	1.8	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz		-	557	-	pF
C _{oss}	output capacitance			-	73	-	pF
C_{rss}	reverse transfer capacitance			-	55	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 15 V; V_{GS} = 10 V; R_{G} = 6 \Omega;$		-	3.1	-	ns
t _r	rise time	$I_{\rm D} = 5.9 {\rm A}$		-	3.4	-	ns
$t_{\rm d(off)}$	turn-off delay time			-	13	-	ns
t _f	fall time			-	4.6	-	ns
Source-d	rain diode						
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 1 A		-	0.76	1	V
		V _{GS} = 0 V; I _S = 1 A; T _j = 125 °C		-	0.61	-	V
ls	body-diode continuous current	T _a = 25 °C		-	-	2	A
t _{rr}	reverse recovery time	V_{GS} = 0 V; I _S = 5.9 A; di/dt = 100 A/µs		-	12	-	ns
Q _{rr}	reverse recovered charge			-	5.0	-	nC
I _{rrm}	reverse recovery current			-	0.7	-	А

N-Channel Silicon MOSFET

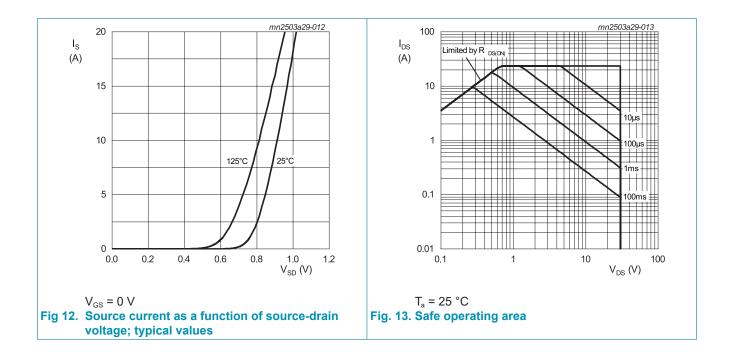


N-Channel Silicon MOSFET

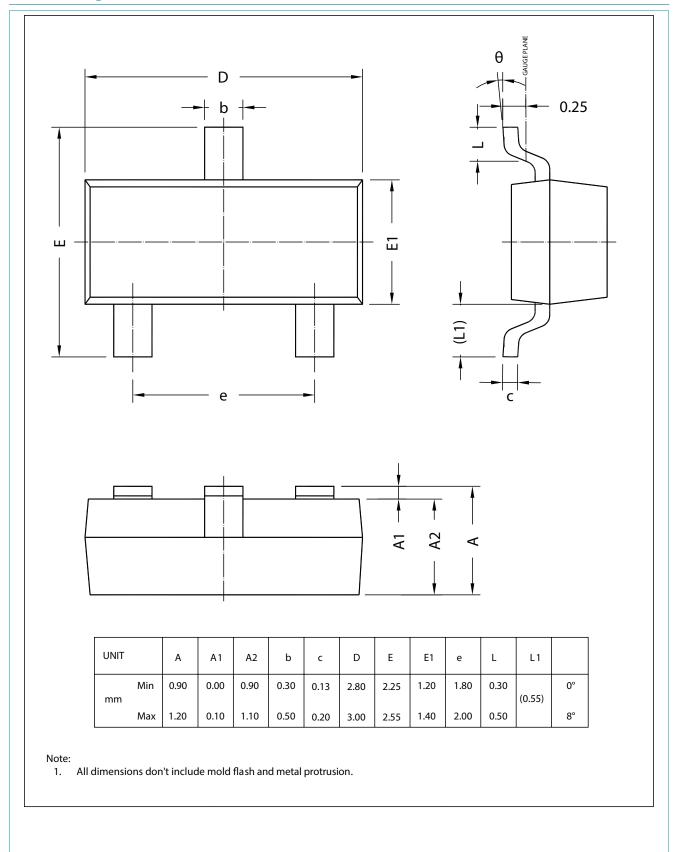


N-Channel Silicon MOSFET

WMS30N250K



11. Package outline



WMS30N250K

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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